

MJ15003 Transistors

Si NPN Power BJT

Military/High-Rel N

$V_{(BR)CEO}$ (V) 140 \ddot{o}

$V_{(BR)CBO}$ (V) 140

$I_{(C)}$ Max. (A) 20

Absolute Max. Power Diss. (W) 250

Maximum Operating Temp (θC) 175 \ddot{o}

$I_{(CBO)}$ Max. (A) 100 $\mu\ddot{a}$

@ $V_{(CBO)}$ (V) (Test Condition)

$V_{(CE)sat}$ Max. (V)

@ $I_{(C)}$ (A) (Test Condition)

@ $I_{(B)}$ (A) (Test Condition)

$h_{(FE)}$ Min. Current gain. 25

$h_{(FE)}$ Max. Current gain. 150

@ $I_{(C)}$ (A) (Test Condition) 5.0

@ $V_{(CE)}$ (V) (Test Condition) 2.0

$f_{(T)}$ Min. (Hz) Transition Freq 2.0M

@ $I_{(C)}$ (A) (Test Condition)

@ $V_{(CE)}$ (V) (Test Condition)

$t_{(d)}$ Max. (s) Delay time.

$t_{(r)}$ Max. (s) Rise time

$t_{(on)}$ Max. (s) On time.